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Effect of environmental coupling on tunneling of quasiparticles in Josephson junctions

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We study quasiparticle tunneling in Josephson tunnel junctions embedded in an electromagnetic environment. We identify tunneling processes that transfer electrical charge and couple to the environment in a way similar to that of normal electrons, and processes that mix electrons and holes and are thus creating charge superpositions. The latter are sensitive to the phase difference between the superconductor and are thus limited by phase diffusion even at zero temperature. We show that that term is suppressed in many environments, thus leading to lower quasiparticle decay rates and thus better superconductor qubit coherence than previously expected.

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The physics of micro and nanoscale Josephson junctions is a paradigmatic application of macroscopic dissipative quantum mechanics of open systems[1–3]. This, on the one hand, makes them ideal test-beds for that theory, with largely tunable parameters[4,5]. On the other hand, Josephson junctions have an ample range of applications in sensing[6], amplification[7], metrology[8] and quantum information processing[9–12]. For these applications, it is imperative to thoroughly understand the dissipative quantum physics of Josephson Junctions in order to achieve optimal device performance.

Most older work on this topic has focused on the *transport* properties of Josephson junctions, their current-voltage and noise characteristics. The ‘P(E)’-theory of treating environmental fluctuations[3,13] has emerged as a powerful tool in the case of small junctions when (Josephson or quasiparticle) tunneling can be treated perturbatively.

For applications in quantum computing, another question in this framework has emerged[14,15]: Rather than computing current-voltage characteristic, the total quasiparticle transition rate is the quantity of interest. This is important because quasiparticle transitions in any direction are highly detrimental to qubit coherence[16]. References [14–18] study this problem in an approach that is perturbative in the coupling to the environment as measured by the environmental impedance in units of the quantum resistance $R_Q = h^2/e \simeq 25.5\ k\Omega$. In this paper we are going to generalize that study to arbitrary system-environment interaction strength. We are going to show that some of the processes mix the electron-like and hole-like branches of the quasiparticle spectrum. These are generally phase-dependent but easily suppressed by the environment. These observations lead to slower relaxation than expected in previous work.

We formulate the mathematical description of quasiparticle tunneling in an environment. We start from the Hamiltonian

$$\hat{H} = \hat{H}_{\mathrm{BCS},1} + \hat{H}_{\mathrm{BCS},2} + \hat{H}_T + \hat{H}_{\mathrm{env}} + \hat{H}_{\mathrm{env-c}}. \qquad (1)$$

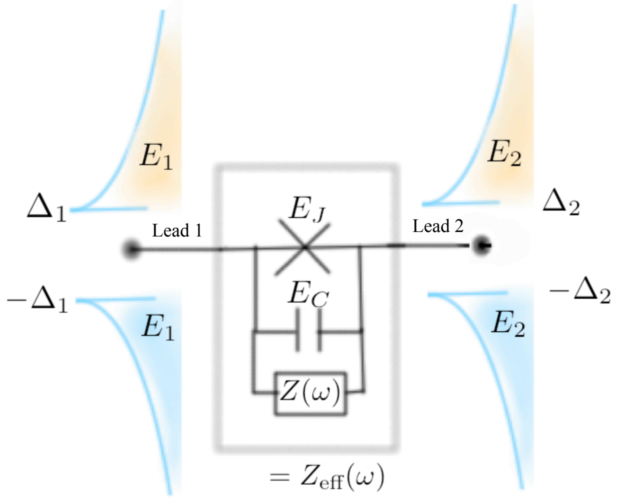

FIG. 1: Quasiparticle processes labeled by their dispersion connected to an external circuit. By linearization, the Josephson circuit is replaced by an effective impedance.

Here, we have the BCS Hamiltonians[19,20]in mean field form describing the two electrodes

$$\begin{aligned}\hat{H}_{BCS,i} &= \sum_{k,\sigma} (\xi_k - \mu_i)\, \hat{c}^\dagger_{k,\sigma,i} \hat{c}_{k,\sigma,i} \\ &\quad + \Delta_i \sum_k \hat{c}_{k,\uparrow,i} \hat{c}_{k,\downarrow,i} + \Delta_i^* \sum_i \hat{c}^\dagger_{k,\uparrow,i} \hat{c}^\dagger_{k,\downarrow,i}\end{aligned} \qquad (2)$$

where $\xi_k = \frac{\hbar^2 k^2}{2m}$ is the kinetic energy of the electron, μ_i is the chemical potential in superconductor $i = 1, 2$, being $\mu_1 = E_F$ and $\mu_2 = E_F + eV$ where V is the applied voltage. We keep $\Delta_i = |\Delta|\, e^{i\phi_{1/2}}$ complex in order to allow for a phase bias. The tunneling Hamiltonian is

$$\hat{H}_T = \sum_{kl} \left(T_{kl} \hat{c}^\dagger_{k,\sigma,1} \hat{c}_{l,\sigma,2} + T^*_{kl} \hat{c}^\dagger_{k,\sigma,2} \hat{c}_{l,\sigma,1} \right) \qquad (3)$$

Before discussing the electromagnetic environment, we diagonalize the BCS Hamiltonians, eq. (2) through the Bogoliubov transformation:

$$\begin{aligned} \hat{c}_{k\uparrow} &= u^*_k \hat{\gamma}_{k\uparrow} + v_k \hat{\gamma}^\dagger_{-k\downarrow}, \\ \hat{c}^\dagger_{-k\downarrow} &= -v^*_k \hat{\gamma}_{k\uparrow} + u_k \hat{\gamma}^\dagger_{-k\downarrow}. \end{aligned}$$

Here, the BCS coherence factors are defined

$$u_{k,i} = \sqrt{\frac{1}{2}\left(1 + \frac{\xi_{k,i} - \mu_i}{E_{k,i}}\right)} e^{i\phi_i/2} \qquad (4)$$

$$v_{k,i} = \sqrt{\frac{1}{2}\left(1 - \frac{\xi_{k,i} - \mu_i}{E_{k,i}}\right)} e^{-i\phi_i/2} \qquad (5)$$

where we introduced the quasiparticle energy $E_{k,i} = \sqrt{(\xi_{k,i} - \mu_i)^2 + |\Delta|^2}$. This allows us to rewrite the tunneling Hamiltonian, eq. 3 in the following form

$$\begin{aligned} \hat{H}_T &= \sum_{k,\sigma=\uparrow,\downarrow} \left(T_{kl} |u_{k1} u_{l2}| e^{i\phi/2} - T^*_{-l-k} |v_{k1} v_{l2}| e^{-i\phi/2} \right) \\ &\quad \times \left(\hat{\gamma}^\dagger_{k\sigma 1} \hat{\gamma}_{k\sigma 2} + \hat{\gamma}^\dagger_{-k\sigma 2} \hat{\gamma}_{-l\sigma 1} \right) + H_{T2} \qquad (6) \end{aligned}$$

where we introduced the phase difference $\phi = \phi_1 - \phi_2$. The term $\hat{H}_{T2}$ contains operators that change the number of quasiparticles by two, i.e., contain terms of the structure $\hat{\gamma}\hat{\gamma}$ and $\hat{\gamma}^\dagger\hat{\gamma}^\dagger$ hence changing the total number of quasiparticles in the setup, which do not contribute to the quasiparticle rate –these terms contribute to Josephson and Andreev processes. We now want to evaluate the Fermi's golden rule rate for a transition that transfers a quasiparticle from the electrode 1 to the electrode 2. The relevant matrix element is

$$\begin{aligned} &\langle (N_1 - 1)_{k\sigma}, (N_2 + 1)_{l\sigma} \left| \hat{H}_T \right| N_{1k\sigma}, N_{2l\sigma} \rangle = \\ &\qquad T_{kl} e^{i\phi/2} \left| u_{k1} u_{l2} \right| - T^*_{-k-l} e^{-i\phi/2} \left| v_{k1} v_{l2} \right| \end{aligned}$$

We now use that for a nonmagnetic barrier, $T_{kl} = T^*_{-k-l}$ can be chosen real. In the Fermi's golden rule transition rate, we need the absolute square

$$\begin{aligned} &\left| \langle (N_1 - 1)_{k\sigma}, (N_2 + 1)_{l\sigma} \left| \hat{H}_T \right| N_{1k\sigma}, N_{2l\sigma} \rangle \right|^2 \\ &\qquad = T^2_{kl} \left(|u|^2 + |v|^2 - 2|uv| \cos\phi \right) \end{aligned}$$

where $u(E, E') = |u_1(E) u_2(E')|$ and $v = |v_1(E) v_2(E')|$ with $u_{1/2}(E)$ and $v_{1/2}(E)$ given by the BCS coherence formulae, eqs. (4) and (5) Thus, the transition probability contains an interference term that is sensitive to the phase bias of the junction. This term describes a process that, even though it transfers a genuine quasiparticle from electrode 1 to electrode 2, it actually consists of a superposition of electron and hole transfer, i.e., it is not diagonal in charge space, see the diagrammatic representation in fig. 2. We will see later on how this is important in the sensitivity to environment. This term bears analogy to the famous $\cos\phi$ term in the Josephson effect[21–24]. Refs. [14,15] have studied the unbiased, $\phi = 0$ limit of this formula.

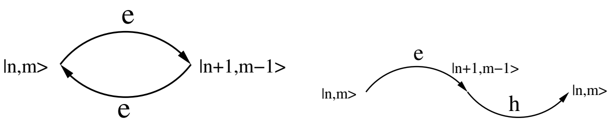

FIG. 2: Diagrammatic representation of the different contributions to the quasiparticle tunneling matrix elements. Left: Processes closed in quasiparticle and in charge space, right: quasiparticle process that creates charge superpositions. The typical state $|n, m\rangle$ represents n particles in the lead 1 and m particles in the lead 2.

In order to capture the influence of the environment, we apply the ideas of $P(E)$-Theory[3]. There, the environmental Hamiltonian is described by an oscillator bath $\hat{H}_{\text{bath}} = \sum_n \omega_n \hat{a}^\dagger_n \hat{a_n}$ and couple the oscillators linearly to our quasiparticle system $\hat{H}_{env-c} = \hat{N}_1 e \delta\hat{V}$, where we assume that only the first reservoir fluctuates - this corresponds to a specific choice of gauge. The total number and voltage operators are

$$\hat{N}_1 = \sum_{k,\sigma} \hat{c}^\dagger_{k\sigma 1} \hat{c}_{k\sigma 1}, \quad \delta\hat{V} = \sum \lambda_i \left(\hat{a}_i + \hat{a}^\dagger_i \right). \qquad (7)$$

We can now work out the total tunneling rate by summing over momentum states at constant energy from the initial state $|i\rangle = |R\rangle|E\rangle$ to the final state $|f\rangle = |R'\rangle|E'\rangle$ and considering that the matrix element of environmental Hamiltonian $\langle E|T_{kq}\gamma^{1\dagger}_{q\sigma}\gamma^2_{k\sigma}|E'\rangle$ thermal distribution of quasiparticles. The transition rate formally can be written

$$\begin{aligned} \vec{\Gamma}_1(V) = \frac{2\pi}{\hbar} \int_{-\infty}^{\infty} dE dE' \, D_1(E) D_2(E') \\ \times f_1(E)[1 - f_2(E')] P_{\text{tot}}(E, E') \qquad (8) \end{aligned}$$

where D_i is the reduced density of states and f_i is the corresponding distribution functions on the lead i. We consider here that the nonequilibrium quasiparticle tunneling keeps the system in thermal and chemical-potential equilibrium. The influence of the external circuitry on quasiparticle tunneling is encoded in the dressed vertex $P_{\text{tot}}(\epsilon)$, the probability density for exchanging energy ϵ with the environment. From the Fermi's golden rule the tunneling transition rate can be written in more detail as

$$\vec{\Gamma_1}(V) \;=\; \frac{1}{e^2 R_N}\int_{-\infty}^{\infty} dE dE' D_1(E) D_2(E') f_1(E)(1-f_2(E')) \sum_{R,R'} |\langle R'|H_T|R\rangle|^2 P_\beta(R)\delta(E+eV-E'+E_R-E_{R'})$$

$P_\beta(R) = \langle R|\rho_\beta|R\rangle$ for $\rho_\beta = e^{-\beta H_{env}}/\sum e^{-\beta H_{env}}$ and the arrow on Γ indicates the direction of tunneling from the lead 1 to 2. R_N is the tunnel resistance of the junction in the normal state. By expanding the Dirac delta as a temporal integral $\delta(x) = (2\pi\hbar)^{-1}\int_{-\infty}^{\infty} dt e^{-\frac{i}{\hbar}xt}$ and writing the operator $\langle R'|e^{-E_{R'}t}\hat{H}_T e^{E_R t}|R\rangle = \langle R'|\hat{H}_T(t)|R\rangle$ the time evolution of the Hamiltonian makes the rate to become proportional to $\langle\langle H_T^q(t)\, H_T^q(0)\rangle\rangle$, where $\langle\langle \cdots \rangle\rangle = \sum_{R,R'}\langle R'|\cdots\rho_\beta|R\rangle$. Substituting the tunneling Hamiltonian into this formula one gets $\langle\langle H_T(t)\, H_T(0)\rangle\rangle = \langle\langle\left(ue^{i\phi(t)/2} - ve^{-i\phi(t)/2}\right)\left(ue^{-i\phi(0)/2} - ve^{i\phi(0)/2}\right)\rangle\rangle$. Taylor expanding the exponents and reordering it is easy to check $\left\langle e^{\pm i\phi(t)} e^{\mp i\phi(0)}\right\rangle \sim e^{\langle(\phi(t)-\phi(0))\phi(0)\rangle}$ and $\left\langle e^{\pm i\phi(t)} e^{\pm i\phi(0)}\right\rangle \sim e^{-\langle(\phi(t)+\phi(0))\phi(0)\rangle}$. Susbstituting this one can get $\langle H_T^q(t)\, H_T^q(0)\rangle = \left(\left(u^2+v^2\right)e^{\langle\phi(t)\phi(0)\rangle/4} - 2uve^{-\langle\phi(t)\phi(0)\rangle/4}\right)e^{-\langle\phi(0)\phi(0)\rangle/4}$.

This makes the transition rate to become

$$\begin{aligned}\vec{\Gamma_1}(V) \;=\; & \frac{4}{e^2 R_N}\int dE dE' \int \frac{dt}{2\pi\hbar} e^{\frac{i}{\hbar}(E+eV-E')} D_1(E) D_2(E') f_1(E)(1-f_2(E')) \\ & \times\left(\left(u^2+v^2\right)e^{\frac{\langle\phi(t)\phi(0)\rangle}{4}} - 2uve^{-\frac{\langle\phi(t)\phi(0)\rangle}{4}}\right)e^{-\frac{\langle\phi(0)\phi(0)\rangle}{4}} \qquad (9)\end{aligned}$$

where $u(E,E') = |u_1(E)u_2(E')|$ and $v = |v_1(E)v_2(E')|$ with $u_{1/2}(E)$ and $v_{1/2}(E)$ given by the BCS formulae, eqs. (4) and (5).

The vertex probability is defined as the probability density for exchanging energy ϵ between system and the environment and is defined formally as

$$P_{\rm tot}(E,E') = \int_{-\infty}^{\infty} \frac{dt}{2\pi\hbar}\, e^{J(t)+\frac{i}{\hbar}(E+eV-E')t} \qquad (10)$$

By comparing eq. (8) and (9) one can correctly expect the definition $e^{J(t)} = \left(u^2+v^2\right)e^{-J_s(t)} - 2uve^{-J_a(t)}$, where $e^{J_s(t)} = \left\langle e^{\phi(t)/2} e^{-i\phi(0)/2}\right\rangle \sim e^{-\langle(\phi(t)-\phi(0))\phi(0)\rangle/4}$ and $e^{J_a(t)} = \left\langle e^{\phi(t)/2} e^{i\phi(0)/2}\right\rangle \sim e^{-\langle(\phi(t)+\phi(0))\phi(0)\rangle/4}$. From these equalities one can simplify the definitions to be $J_s(t) = \langle(\delta\phi(t) - \delta\phi(0))\delta\phi(0)\rangle/4$ and $J_a(t) = -\langle(\delta\phi(t)+\delta\phi(0))\delta\phi(0)\rangle/4$, where the phase factors are given by

$$\delta\phi(t) = \frac{e}{\hbar}\int_0^t dt'\,\delta V(t'). \qquad (11)$$

Note that in the definitions we considered that the mean value of the phase is not physically relevant as long as the effect of environment is summarized into the presence of phase fluctuations about this mean value. The symmetric combination $J_s(t)$ captures all-electron and all-hole processes and the corresponding vertex coincides with the all-electron $P(E)$ known from Ref.3

$$P_S(E) = P(E) = \int dt\, e^{-iEt} e^{-J_s(t)}. \qquad (12)$$

On the other hand, $J_a(t) = \langle(\delta\phi(t)+\delta\phi(0))\delta\phi(0)\rangle/4 = J_s(t) + \left\langle\delta\phi^2(0)\right\rangle/2$ captures processes that mix electrons and holes.

Other than J_s, this correlation function does not vanish at $t=0$, rather, $J_a(0) = \left\langle\delta\phi^2(0)\right\rangle/2$ captures zero-point fluctuation. Consequently,

$$\frac{P_a(E)}{P_s(E)} = \frac{e^{-\frac{\left\langle\delta\phi^2(0)\right\rangle}{2}}\int_0^{\mathcal{T}} dte^{-J(t)+\frac{i}{\hbar}Et}}{\int_0^{\mathcal{T}} dte^{J(t)+\frac{i}{\hbar}Et}} \overset{\mathcal{T}=0}{\rightarrow} e^{-\frac{\left\langle\delta\phi^2(0)\right\rangle}{2}} \qquad (13)$$

$P_s(E)$, $P_a(E)$ are not normalized as they are density probabilities. We can understand this as follows: Even though electron-hole mixing processes are diagonal in the Fock space of quasiparticles, they are off-diagonal in charge space. The electromagnetic noise couples to these electrical charges. The environmental modes dress the charge in an attempt to measure charge and localize it. This has an analogy: Creation of a superposition of charge states occurs, following the charge-flux uncertainty relation, whenever the phase across a Josephson junction is becoming localized, i.e., when a Josephson junction is behaving classically. Thus, on the one hand, the scaling factor in eq. (13), directly measures the degree of charge localization. On the other hand, research aiming at maximum supercurrent (hence maximally localized phase and maximally extended charge) in small Josephson junctions in a dissipative environment finds $\exp(-\langle\phi(0)^2\rangle/2)$ to be the relevant reduction factor[25,26].

In order to compute $J_{s/a}$, we can show, by introducing an oscillator bath model and matching its properties to the fluctuation-dissipation theorem as it describes Johnson-Nyquist noise. Applying the standard procedures used in $P(E)$-theory, we find

$$S(t) = \langle \delta\phi(t)\delta\phi(0)\rangle = 2\int_{-\infty}^{\infty} \frac{d\omega}{\omega}\frac{\mathrm{Re}Z_{\mathrm{eff}}(\omega)}{R_K}\frac{e^{-i\omega t}}{1-e^{-\beta\hbar\omega}} \tag{14}$$

Notably, this integral seems to diverge at its infrared end, where it formally appears to be $\simeq \int \frac{d\omega}{\omega} Z_{\mathrm{eff}}(0)$ at $T = 0$ and $\propto T \int \frac{d\omega}{\omega^2}\mathrm{Re}Z_{\mathrm{eff}}(0)$ at $T > 0$. In the combination $J_s(t) = S(t) - S(0)$ this divergence is regulated, but the same argument does not apply to $J_a(t) = S(t) + S(0)$. Thus, if $Z_{\mathrm{eff}}(0) \neq 0$, eq. (13) enforces $P_a = 0$, meaning that all electron-hole mixed processes would disappear. We will see later that this does not occur in standard physical environments.

The final expression for the probability density $P(E, E')$ is thus

$$\begin{aligned} P_{\mathrm{tot}}(E,E') &= \int \frac{dt}{2\pi\hbar}\, e^{-i(E+eV-E')t} e^{-\frac{S(0)}{2}} \\ &\times \left[(u^2+v^2)e^{\frac{S(t)}{2}} - 2uve^{-\frac{S(t)}{2}}\right] \end{aligned} \tag{15}$$

In order to evaluate the typical $P_{s/a}(E)$ and the resulting tunneling rates, we need to project likely models of the electromagnetic environment encoded in Z_{eff}. Following the RCSJ models and its microscopic analogues[1,2,27,28], we consider the quasiparticle channel to be put in parallel to the supercurrent, Josephson channel, the junction capacitance, and an external impedance $Z(\omega)$, see Fig. (1). We model the linear impedance of the Josephson channel by its Josephson inductance $L_J = \Phi_0/(2\pi I_c)$. The total effective impedance of this parallel setup leads to

$$\mathrm{Re}Z_{\mathrm{eff}} = \frac{\omega^2 \mathrm{Re}\,(Z)}{C^2|Z|^2}\frac{1}{\left(\omega^2-\omega_p^2\right)^2 + \omega\omega_P^3\frac{\mathrm{Im}Z}{|Z|^2} + \frac{\omega^2}{C^2|Z|^2}} \tag{16}$$

with $\omega_p = (CL_J)^{-1/2}$ is the junction's plasma frequency. In the case of a simple resistor or lossless transmission line, $Z(\omega) = R$ and we find

$$\mathrm{Re}[Z_{\mathrm{eff}}] = \frac{\omega^2}{RC^2}\frac{1}{(\omega^2-\omega_p^2)^2 + \omega^2/(RC)^2} \tag{17}$$

Here, we can observe that at low frequencies, $\mathrm{Re}Z_{\mathrm{eff}} \propto \omega^2$. Physically, the reason for this is that the noise from the resistor gets shunted through the Josephson junction at low frequencies and does not affect the quasiparticle channel. Thus, although P_a will be normalized to a value smaller than unity, the scenario of it scaling all the way to zero does not occur. This is consistent with the fact that phase qubits do show a zero-voltage current. The same general conclusion holds for other physical environments tested.

Given the high quality of qubit junctions, it is appropriate to start from the limit of an infinite quality factor, $R \to \infty$. In that case, the effective impedance reduces to

$$Z_{\mathrm{eff}} = \frac{\pi}{2C}\left[\delta\left(\omega-\omega_p\right) + \delta\left(\omega+\omega_p\right)\right]. \tag{18}$$

Introducing the dimensionless parameter $\rho = \pi\frac{Z_0}{R_K}$, where $Z_0 = \sqrt{\frac{L_J}{C}}$ is the wave impedance of the junction, and given the definition of $Z_{eff} = \pi/2C\left(\delta(\omega-\omega_p)+\delta(\omega+\omega_p)\right)$ and that $\omega_p = 1/\sqrt{L_J C}$ and $L_J = \Phi_0/2\pi I_c$ we can find that $S(0)/2 = \rho = \pi Z_0/R_K$. For the total environmental probability we use the result of Ref.[3]

$$P(E) = \sum_{k=-\infty}^{\infty} p_k(\rho,\omega_{P,}T)\delta(\omega - k\omega_p) \tag{19}$$

which has the form of a series of sidebands, corresponding to the emission / absorption of k photons to/from the plasma mode. The weights in the low temperature limit of $k_B T \ll \hbar\omega_p$ is Poissonian $p_k\left(\rho,\omega_p\right) = e^{-\rho}\rho^k/k!$. This coincides with that of[15] in the limit of $\rho \to 0$. The total quasiparticle tunneling rate hence reads

$$\begin{aligned} \vec{\Gamma_1} &= \frac{4}{R_T e^2}\sum_{n=-\infty}^{\infty}\int_{\Delta}^{\infty} dE\, D_L(E)D_R(E+n\hbar\omega_p)f_1(E)(1-f_2(E+n\hbar\omega)) \\ &\times \left[\left(u^2(E,E+n\hbar\omega)+v^2(E,E+n\hbar\omega)\right)e^{\frac{S(t)}{2}} - 2u(E,E+n\hbar\omega)v(E,E+n\hbar\omega)e^{-\frac{S(t)}{2}}\right]e^{-\rho}p_n(\rho,\omega_p,T) \\ &= \sum_{n=-\infty}^{\infty}\Gamma_{1n} \end{aligned}$$

For large capacitance junctions where the phase is localized the exponential can be Taylor expanded, thus one can get the approximate result at low phase limit by the approximation $\left(u^2+v^2\right)\exp\left[S(t)/2\right] -$

$2uv\exp\left[-S(t)/2\right] \sim (u-v)^2 + (u+v)^2 S(t)/2$. This approximate limit result is consistent with the results taken from Ref.[14] except that ours show that there is a prefactor $\exp(-\langle \delta\phi(0)^2\rangle/2)$ in the rate that is missing in previous works that can reduce the quasiparticle environmentally mediated transition rate.

Note that for the special case of $n = 1$ we find $\Gamma_{\mathrm{bare,1}} e^{-\rho} + \Gamma_{\mathrm{dr,1}} e^{-\rho}$ where $\Gamma_{\mathrm{bare,n}}$ corresponds to the bare quasiparticle tunneling rate

$$\Gamma_{\mathrm{bare}} = \frac{4}{R_T e^2}\int_\Delta^\infty dE\, f_1(E)(1-f_2(E)) \tag{20}$$

under a bias voltage controlled by the Josephson-type relation $V = n\hbar\omega/e$ and

$$\Gamma_{\mathrm{dr,n}} \sim \frac{\sqrt{2}}{RC}\left(\frac{\Delta}{n\omega}\right)^{3/2}\frac{n_{\mathrm{qp}}}{D(E_F)\Delta} \tag{21}$$

where $D(E_F)$ is the density of states in the leads at the Fermi energy and n_{qp} the density of quasiparticles in the sample.

Let us now compute the rate. For this to be done we need to know the explicit energy dependence of the transition rate. Using eq. (4) and (5) one can show that

$$\begin{aligned}(u_1u_2)^2 + (v_1v_2)^2 &= \frac{1}{2}\left(1 + \frac{\xi_1\xi_2}{E_1E_2}\right)\\ u_1u_2v_1v_2 &= \frac{1}{4}\sqrt{\left(\frac{\xi_1\xi_2}{E_1E_2}\right)^2 + \frac{\Delta_1^2}{E_1^2} + \frac{\Delta_2^2}{E_2^2} - 1}\end{aligned} \tag{22}$$

Substituting the density of states and the coherence factors in the transition rate we arrive at the complete unperturbed formula for nonequilibrium quasiparticle tunneling

$$\Gamma = \frac{2}{e^2R_N}\sum_{n=-\infty}^{\infty} e^{-2\rho}\frac{\rho^n}{n!}\int_\Delta^\infty dE\, f_1(E)(1-f_2(E+n\hbar\omega))\frac{E\left(E+n\hbar\omega_p\right)e^{\frac{S(t)}{2}} - \Delta_1\Delta_2 e^{-\frac{S(t)}{2}}}{\sqrt{\left(E^2-\Delta_1^2\right)\left(\left(E+n\hbar\omega_p\right)^2-\Delta_2^2\right)}} \tag{23}$$

This is one of the main results of this paper based on which one can calculate the rate for any subsystem. As one can see the asymmetric term $P_a(E)$ is reduced, according to eq. 13, by a factor of $e^{-2\rho}$. This leads to a difference in $O(\rho)$ that occurs in our approach accounting for zero-point fluctuations in the impedance as well as phase fluctuations. For phase qubits, whose impedance is engineered to be $Z_0 \simeq 50\Omega$ this correction does not qualitatively change the physics, however, improves the quality of fits to the data. In other type of qubits with higher impedance these corrections will be crucial. A qubit relaxation/excitation experiments involving nonequilibrium quasiparticles[14], will attempt to relax the qubit energy splitting which is $\simeq \omega_p$ into quasiparticles, hence, only the main band is relevant.

Overall normalization of $P(E)$ means that the appearance of sidebands generally lowers the main resonance. In order to study other types of qubits, we can easily show that

$$\rho = \sqrt{\frac{E_c}{8E_J}}. \tag{24}$$

For a transmon, $E_J/E_c \approx 30$ and for a flux qubit ≈ 50, making this correction large enough to be visible in a reduction of the quasiparticle rate whereas the $\cos\phi$-term will not be suppressed altogether. More explicitly, for a transmon we get a deviation of around 7% from the perturbative approximation $(1 - e^{-2\rho} \approx 2\rho)$ and for a flux qubit we get a deviation of around 5%. For a traditional charge qubit, ρ is large, leading to a different regime. From[29], $E_J/E_c \approx 0.35$ in a typical charge qubit case leading to a large deviation of around 40% from the perturbative approximation.

We are now studying the opposite case, an environmental mode that is overdamped by an external impedance. Overdamping means the width of the resonance in Z_{eff}, eq. 17 is larger than its frequency, i.e. $\omega_p RC \ll 1$ or equivalently $R \ll Z_0$. In that case, to lowest order in the small parameter $r = \frac{R}{Z_0}$ is, the poles of Z_{eff}, eq. 17 are at $\omega = \pm i\gamma$ and at $\omega = \pm i\gamma r^2$ where $\gamma = 1/RC$. Note that unlike other work for overdamped oscillators[30]we keep the next-to leading order which keeps the second set of poles to zero, rendering the quasiparticle current nonzero in view of eq. (15). This will have an important consequence later on. We can now, in the overdamped case, rewrite eq. (17) as

$$Z_{\mathrm{eff}} \simeq R\gamma^2\frac{1}{1-r^4}\left[\frac{1}{\omega^2+\gamma^2} - \frac{r^4}{\omega^2+\gamma^2r^4}\right]. \tag{25}$$

This can be read as the difference between two Ohmic environments with a Drude cutoff[30]. This allows us to rely on known results[3,5,13,30] for computing $J(t)$. Here, we focus on the zero-temperature regime. We find for the zero-point term $S(0) = -\frac{2R}{R_K}\log r$.

Now, interestingly, this will be a large positive term for $r \to 0$ which can be achieved by going to small ω_p, i.e.

the uv -term in eq. (15) will be suppressed by a factor r^{4R/R_K} to a very small value.

It is known[13]is that for $Z_d = \frac{R_0}{1+\omega^2/\omega_0^2}$ we have

$$\dot{J}_S(t) = \frac{R_0\omega_0}{R_K}\left[e^{-\omega_0\tau}E_1(-\omega_0\tau) - e^{\omega_0\tau}E_1\left(\omega_0\tau\right)\right] \quad (26)$$

and that for long times, $\omega_0\tau \to \infty$ this reduces to $J_S(t) = -\frac{2R_0}{R_K}\left(\log\omega_c t + \gamma_e + i\frac{\pi}{2}\right)$ where $\gamma_e \simeq 0.5772$ is the Euler-Mascheroni constant. For short times, $\omega_0\tau \ll 1$, we find $J(t) = i\pi\alpha\omega_0\pi t$. We can now find $P(E)$ in three regimes. For $E \ll \gamma, \gamma r^2$, both terms in eq. 25 should be treated in the long-time limit. In lowest order in r we find

$$J(t) = -\frac{4R}{R_K}\log r \quad (27)$$

i.e., no time-dependence, in agreement with the fact that the environment is super-Ohmic at these low frequencies, see eq. 25. This leads to $P_s(E) = r^{4\rho}\delta(E)$.

In the intermediate regime, $\gamma r^2 \ll E \ll \gamma$, we can combine short and long-time limit as

$$J(t) = -\frac{R_0}{R_K}\left[\log\gamma t + \gamma_e + i\frac{\pi}{2} - i\pi\gamma r^2 t\right] \quad (28)$$

This leads to an Ohmic $P(E)$ that is energetically shifted by $\delta E = \frac{R_0}{R_K}\pi\gamma r^2 = \frac{R^2}{LR_K}$. This results in

$$\begin{aligned} P(E) \;=\; & \frac{e^{-2\gamma_e R_K/R}}{\Gamma(2R_K/R)}\frac{1}{E}\left(\frac{\pi R_K}{R}\frac{E}{E_c}\right)^{2R_K/R} \\ & \times\left(1 + \left(\frac{2R_K}{R} - 1\right)\frac{\delta E}{E}\right) \quad (29)\end{aligned}$$

where we introduced the charging energy $E_c = \frac{e^2}{2C}$. Finally, at large energies hence entirely short times and large energies, $E \gg \gamma$, we can approximate

$$J(t) \simeq \frac{i\pi}{C}t \quad (30)$$

hence leading to a simple capacitive contribution from the junction's charging energy and $P(E, E') = e^{-S(0)}\left(\left(u^2 + v^2\right)e^{S(t)} - 2uve^{-S(t)}\right)\delta\left(E' - E - e^2/2C\right)$.

In conclusion, we have developed the theory of quasiparticle tunneling for superconducting tunnel junctions in an arbitrary linear dissipative environment. We worked out the unperturbed tunneling rate of nonequilibrium quasiparticles in the junction. In the perturbation regime P(E) governs processes of an electron or hole tunneling, which are represented by the diagonal transition matrix elements in charge space. We showed that processes that create charge superpositions are additionally supressed by zero-point fluctuations of the phase. For the case of low damping, quasiparticle tunneling is exchanging energy with the plasma mode in the form of a sequence of sidebands.

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